

# Defect chemistry of a high-k ‘Y5V’ (Ba<sub>0.95</sub>Eu<sub>0.05</sub>)TiO<sub>3</sub> ceramic

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## Abstract

The influence of the sintering temperature ( $T_s$ ) on the structure, dielectric and valence-state properties of (Ba<sub>1-x</sub>Eu<sub>x</sub>)TiO<sub>3</sub> ( $x=0.05$ ) ceramics was investigated using X-ray diffraction (XRD), scanning electron microscopy (SEM), electron paramagnetic resonance (EPR), Raman spectroscopy, and dielectric temperature measurements. An increase in  $T_s$  can increase the solubility limit of Eu in BaTiO<sub>3</sub>. When the  $T_s$  was increased to 1450 °C, a high-k ‘Y5V’ ( $\epsilon'_{RT}=8500$ ) ceramic (C-BE5T) with a single-phase cubic structure was obtained. The dielectric peak shifted rapidly toward lower temperatures with increasing  $T_s$  at a rate of  $-0.46$  °C/K. A symmetric (200) XRD peak, exaggerated grain growth (5.6  $\mu\text{m}$ ), a mixed valence of Eu<sup>2+</sup>/Eu<sup>3+</sup>, an asymmetric main Raman band at 2494 cm<sup>-1</sup> and a weak sharp band at 1516 cm<sup>-1</sup> in the high-wavenumber region are characteristics of cubic symmetry of C-BE5T. The formation of a solid solution of C-BE5T and defect chemistry are discussed.

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## 1. Introduction

Europium-doped barium titanate (BaTiO<sub>3</sub>) ceramics or powders have drawn a great deal of attention because of their luminescence properties [1–4]. In 2005, however, a low-porosity, highly-insulating, dielectric-ageing-resistant, and fine-grained (Ba<sub>1-x</sub>Eu<sub>x</sub>)Ti<sub>1-x/8</sub>O<sub>3</sub> ( $x=0.05$ ) ceramic that exhibited dielectric-temperature stability in a lower temperature range of  $-100$  to  $50$  °C was obtained, accompanied by the appearance of a secondary phase, Eu<sub>2</sub>Ti<sub>2</sub>O<sub>7</sub>, which was formed due to the solubility limit of  $x=0.03$  at a powder sintering temperature of  $1300$  °C [5]. Since then, the valence state and site occupation of Eu ions in the BaTiO<sub>3</sub> lattice and the dielectric properties associated with different charge-compensation mechanisms have been successively investigated [6–10]. Europium may occupy Ba sites as Eu<sup>3+</sup> [6–8] or as mixed Eu<sup>3+</sup>/Eu<sup>2+</sup> [6,9], or may occupy both Ba and Ti sites

as Eu<sup>3+</sup> [9,10]. Eu has been reported to prefer Ba sites to Ti sites but can transfer from Ba sites to Ti sites depending on the Ba/Ti ratio [10]. Electron paramagnetic resonance (EPR) investigations suggested that a self-compensation mode with the amphoteric behavior of Eu ions can occur in (Ba<sub>1-x/2</sub>Eu<sub>x/2</sub>)(Ti<sub>1-x/2</sub>Eu<sub>x/2</sub>)O<sub>3</sub> ( $x=0.05$ ) and results in no reduction of Eu<sup>3+</sup> to Eu<sup>2+</sup> occurring [9]. For (Ba<sub>1-x</sub>Eu<sub>x</sub>)TiO<sub>3</sub> ceramics prepared via a solid-state method, however, no evidence for the valence change of Eu<sup>3+</sup> to Eu<sup>2+</sup> was provided [8]. Eu-doped BaTiO<sub>3</sub> generally exhibits a tetragonal structure and its dielectric peak cannot reach room temperature because of the solubility limit of  $x=0.03$  [5]. A single-phase and high-k ‘Y5V’ (Ba<sub>1-x</sub>Eu<sub>x</sub>)TiO<sub>3</sub> ( $x\leq 0.05$ ) has not been reported to date. (Note: Y5V specification:  $-82\% \leq (\epsilon' - \epsilon'_{RT})/\epsilon'_{RT} \leq +22\%$  in a temperature range of  $-30$  to  $85$  °C)

In this work, (Ba<sub>1-x</sub>Eu<sub>x</sub>)TiO<sub>3</sub> ( $x=0.05$ ) ceramics were prepared at different sintering temperatures ( $T_s$ ) using a cold-pressing ceramic technique. Our objective is to increase the  $T_s$  to increase the solubility limit of Eu in BaTiO<sub>3</sub> to obtain a single-phase cubic ceramic and realize a high-k Y5V behavior. The structural, dielectric and valence-state properties of the

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cubic ( $\text{Ba}_{1-x}\text{Eu}_x$ ) $\text{TiO}_3$  ceramic were investigated using XRD, SEM, ESR, Raman spectroscopy, and dielectric measurements to elucidate the solid solution formation and the defect chemistry. The high-wavenumber Raman and EPR spectra in the cubic phase showed novel features.

## 2. Experimental procedures

( $\text{Ba}_{1-x}\text{Eu}_x$ ) $\text{TiO}_3$  ( $x=0.05$ ) ceramics (abbreviated BE5T) were prepared using a cold-pressing ceramic technique described elsewhere [5]. The final sintering conditions were chosen as 1200, 1250, 1300, 1350, 1400, and 1450 °C for 3 h.  $\text{Eu}_2\text{Ti}_2\text{O}_7$  and  $\text{Eu}_2\text{O}_3$  ceramics were prepared at 1300 °C under the same route as that used for BE5T for Raman scattering analyses and comparison. Powder X-ray diffraction (XRD) measurements were performed between  $20^\circ \leq 2\theta \leq 100^\circ$  in steps of  $0.02^\circ$  using a DX-2700 X-ray diffractometer (Dandong Haoyuan Inc.). Lattice parameters and unit cell volume were calculated by MS Modeling software package (Accelrys Inc.) using Cu  $\text{K}\alpha 1$  radiation ( $\lambda=1.540562 \text{ \AA}$ ). Scanning electric microscopy (SEM) images were obtained using a JSM-6490 SEM (JEOL) operated at 25 kV. The temperature dependence of the dielectric permittivity and loss was measured from  $-75$  to  $200^\circ \text{C}$  with a weak 1 kHz ac electric field using an RCL meter (Fluke PM6306). Electron paramagnetic resonance (EPR) spectra were measured at an X-band frequency of 9.148 GHz from 25 to  $150^\circ \text{C}$  in the sweep range of 50–550 mT using a JES-RE3X spectrometer (JEOL) equipped with a  $\text{Mn}^{2+}$  standard marker. The gyromagnetic values ( $g$  values) were calculated in terms of the third and fourth lines of the  $\text{Mn}^{2+}$  standard sextet marker ( $g_3=2.0327$  and  $g_4=1.9810$ ). Raman spectra of the ceramic powders were measured at room temperature using a LabRAM XploRA Raman spectrometer (Horiba Jobin Yvon), with a 532 nm laser focused on a spot of approximately 3–5  $\mu\text{m}$  in diameter. The Raman spectrometer was equipped with a Linkam-600 heating and cooling stage for temperature-dependent Raman measurements from  $-150$  to  $180^\circ \text{C}$ .

## 3. Results

Powder XRD patterns of all the BE5T ceramics sintered at different sintering temperatures ( $T_s$ ) are shown in Fig. 1. The main perovskite phase was formed at each  $T_s$ . When the  $T_s$  was less than  $1400^\circ \text{C}$ , a small amount of a second phase separated from the main tetragonal perovskite phase. A pyrochlore phase,  $\text{Eu}_2\text{Ti}_2\text{O}_7$  (JCPDS: no. 23-1072), appeared at  $T_s=1250^\circ \text{C}$  and the quantity of this phase gradually decreased with increasing  $T_s$ . For the main tetragonal perovskite phase, the separate (002) and (200) peaks shift toward each as  $T_s$  is increased, as shown in Fig. 2. This shift indicates a decrease in tetragonality. When the  $T_s$  was increased to  $1450^\circ \text{C}$ , the  $\text{Eu}_2\text{Ti}_2\text{O}_7$  phase disappeared and a single-phase ceramic formed, with a symmetric (200) peak characteristic of a cubic structure.

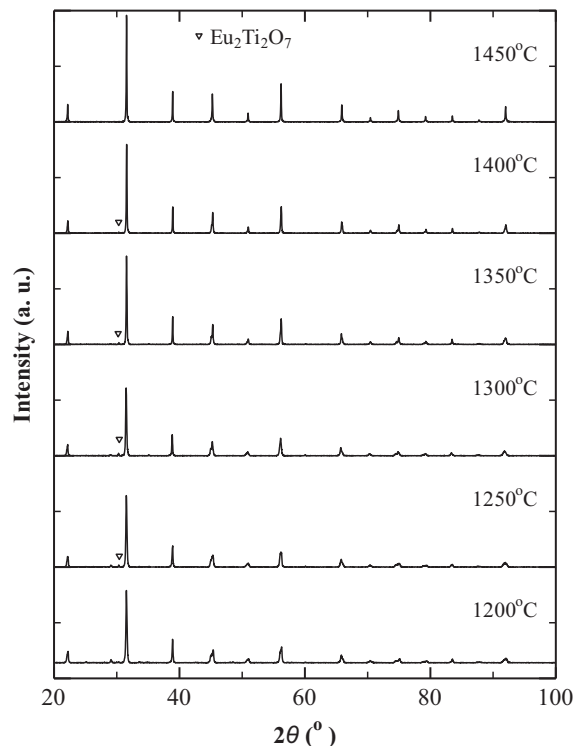


Fig. 1. XRD patterns of BE5T ceramics prepared at different sintering temperatures ( $T_s=1250$ – $1450^\circ \text{C}$ ).

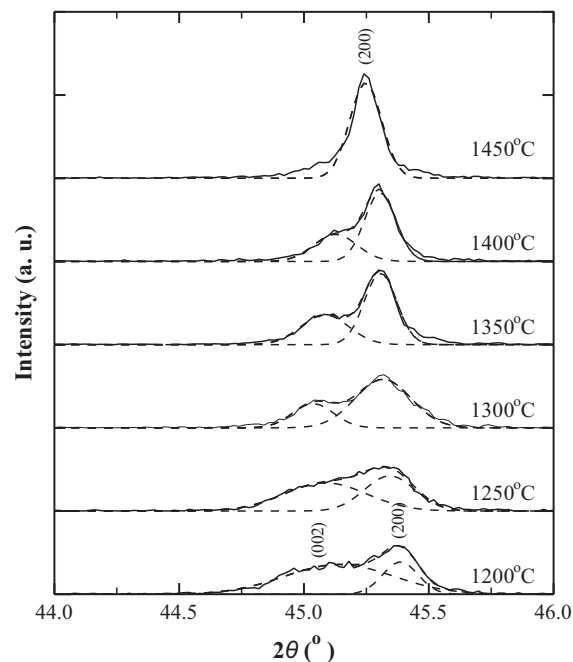


Fig. 2. Gaussian fitting of the XRD peaks in the vicinity of  $45^\circ$  in Fig. 1.

The unit-cell volume ( $V_0$ ) of the cubic BE5T sample (called C-BE5T in the following) was determined to be  $64.31 \text{ \AA}^3$ , which is significantly less than the  $V_0$  ( $65.50 \text{ \AA}^3$ ) of the cubic  $\text{BaTiO}_3$  (JCPDS: no. 31-174). C-BE5T can therefore be considered as a sufficient incorporation of Eu ions into Ba sites in the  $\text{BaTiO}_3$  lattice; otherwise, an expansion of the crystal cells would be observed if Eu entered the Ti sites

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